

# DS26LV31T 3V Enhanced CMOS Quad Differential Line Driver

Check for Samples: DS26LV31T

#### **FEATURES**

- Industrial Product Meets TIA/EIA-422-B (RS-422) and ITU-T V.11 Recommendation
- Military Product Conforms to TIA/EIA-422-B (RS-422)
- Interoperable with Existing 5V RS-422 **Networks**
- Industrial and Military temperature Range
- Guaranteed V<sub>OD</sub> of 2V min Over Operating **Conditions**
- **Balanced Output Crossover for Low EMI** (Typical Within 40 mV of 50% Voltage Level)
- Low Power Design (330 µW @ 3.3V static)
- ESD ≥ 7 kV on Cable I/O Pins (HBM)
- **Guaranteed AC Parameter:** 
  - Maximum Driver Skew: 2 ns
  - Maximum Transition Time: 10 ns
- Pin Compatible with DS26C31
- Available in SOIC and CLGA Packaging

Standard Microcircuit Drawing (SMD) 5962-98584

#### DESCRIPTION

The DS26LV31T is a high-speed quad differential CMOS driver that meets the requirements of both TIA/EIA-422-B and ITU-T V.11. The CMOS DS26LV31T features low static I<sub>CC</sub> of 100 µA MAX which makes it ideal for battery powered and power conscious applications.

Differential outputs have the same V<sub>OD</sub> guarantee (≥2V) as the 5V version.

The EN and EN\* inputs allow active Low or active High control of the TRI-STATE outputs. The enables are common to all four drivers. Protection diodes protect all the driver inputs against electrostatic discharge. Outputs have enhanced ESD protection providing greater than 7 kV tolerance. The driver and enable inputs (DI, EN, EN\*) are compatible with low voltage LVTTL and LVCMOS devices.

### **Connection Diagram**

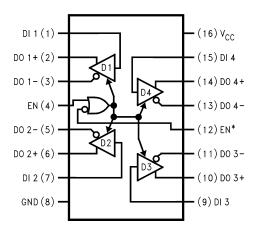


Figure 1. Dual-In-Line Package **Top View** See Package D (R-PDSO-G16)

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## Truth Table<sup>(1)</sup>

| Enabl                  | es  | Input | Outputs |     |  |  |
|------------------------|-----|-------|---------|-----|--|--|
| EN                     | EN* | DI    | DO+     | DO- |  |  |
| L                      | Н   | X     | Z       | Z   |  |  |
| All oth                |     | L     | L       | Н   |  |  |
| combinati<br>enable ir |     | Н     | Н       | L   |  |  |

(1) L = Low logic state X = Irrelevant

H = High logic state

Z = TRI-STATE



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# Absolute Maximum Ratings (1)(2)

| Aboolato maximum ratingo                      |                                 |
|---|---------------------------------|
| Supply Voltage (V <sub>CC</sub> )             | -0.5V to +7V                    |
| Enable Input Voltage (EN, EN*)                | -0.5V to V <sub>CC</sub> + 0.5V |
| Driver Input Voltage (DI)                     | -0.5V to V <sub>CC</sub> + 0.5V |
| Clamp Diode Current                           | ±20 mA                          |
| DC Output Current, per pin                    | ±150 mA                         |
| Driver Output Voltage                         |                                 |
| (Power Off: DO+, DO−)                         | −0.5V to +7V                    |
| Maximum Package Power Dissipation @+25°C      |                                 |
| D0016A Package                                | 1226 mW                         |
| NAD0016A Package                              | 1119 mW                         |
| Derate D0016A Package 9.8 mW/°C above +25°C   |                                 |
| Derate NAD0016A Package 7.5 mW/°C above +25°C |                                 |
| Storage Temperature Range                     | −65°C to +150°C                 |
| Lead Temperature Range Soldering (4 sec.)     | +260°C                          |
| ESD Ratings (HBM, 1.5 kΩ, 100 pF)             |                                 |
| Driver Outputs                                | ≥7 kV                           |
| Other Pins                                    | ≥2.5 kV                         |
|   |                                 |

 <sup>&</sup>quot;Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics specifies conditions of device operation.

# **Recommended Operating Conditions**

|  | Min | Тур | Max  | Units |
|--|-----|-----|------|-------|
| Supply Voltage (V <sub>CC</sub> )                      | 3.0 | 3.3 | 3.6  | V     |
| Operating Free Air Temperature Range (T <sub>A</sub> ) |     |     |      |       |
| DS26LV31T  | -40 | +25 | +85  | °C    |
| DS26LV31W  | -55 | +25 | +125 | °C    |
| Input Rise and Fall Time                               |     |     | 500  | ns    |

<sup>(2)</sup> If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.



## Electrical Characteristics (1) (2)

Over supply voltage and operating temperature ranges, unless otherwise specified

|                  | Parameter   | Test Con  | ditions                                       | Pin      | Min  | Тур   | Max      | Units |
|------------------|---|---|---|----------|------|-------|----------|-------|
| V <sub>OD1</sub> | Output Differential Voltage                           | R <sub>L</sub> = ∞ (No Load)                                  |   | DO+,     |      | 3.3   | 4        | V     |
| V <sub>OD2</sub> | Output Differential Voltage                           | $R_L = 100\Omega$ (Figure 2)                                  |   | DO-      | 2    | 2.6   |          | V     |
| $\Delta V_{OD2}$ | Change in Magnitude of<br>Output Differential Voltage | I <sub>O</sub> ≥ 20 mA  |   |          | -400 | 7     | 400      | mV    |
| $V_{OD3}$        | Output Differential Voltage                           | R <sub>L</sub> = 3900Ω (V.11)<br>Figure 2 and <sup>(3)</sup>  |   |          |      | 3.2   | 3.6      | V     |
| V <sub>oc</sub>  | Common Mode Voltage                                   | $R_L = 100\Omega$ (Figure 2)                                  |   |          |      | 1.5   | 2        | V     |
| ΔV <sub>OC</sub> | Change in Magnitude of Common Mode Voltage            |   |   |          | -400 | 6     | 400      | mV    |
| l <sub>OZ</sub>  | TRI-STATE Leakage<br>Current                          | V <sub>OUT</sub> = V <sub>CC</sub> or GND<br>Drivers Disabled |   |          |      | ±0.5  | ±20      | μA    |
| I <sub>SC</sub>  | Output Short Circuit Current                          | V <sub>OUT</sub> = 0V   | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ |          | -40  | -70   | -150     | mA    |
|                  |   | $V_{IN} = V_{CC}$ or $T_{A}$                                  | $T_A = -55^{\circ}C$ to +125°C (5)            |          | -30  |       | -160     | mA    |
| I <sub>OFF</sub> | Output Leakage Current                                | $V_{CC} = 0V$ , $V_{OUT} = 3V$ or $6$                         | 6V  |          |      | 0.03  | 100      | μΑ    |
|                  |   | V <sub>CC</sub> = 0V, V <sub>OUT</sub> =                      | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ |          |      | -0.08 | -100     | μΑ    |
|                  |   | -0.25V  | $T_A = -55$ °C to +125°C                      |          |      |       | -200     | μΑ    |
| $V_{IH}$         | High Level Input Voltage                              |   |   | DI,      | 2.0  |       | $V_{CC}$ | V     |
| V <sub>IL</sub>  | Low Level Input Voltage                               |   |   | EN,      | GND  |       | 0.8      | V     |
| I <sub>IH</sub>  | High Level Input Current                              | $V_{IN} = V_{CC}$   |   | EN*      |      |       | 10       | μΑ    |
| I <sub>IL</sub>  | Low Level Input Current                               | V <sub>IN</sub> = GND   |   |          | -10  |       |          | μΑ    |
| $V_{CL}$         | Input Clamp Voltage                                   | I <sub>IN</sub> = −18 mA                                      |   |          |      |       | -1.5     | V     |
| I <sub>CC</sub>  | Power Supply Current                                  | No Load, V <sub>IN</sub> (all) = V <sub>CC</sub>              | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | $V_{CC}$ |      |       | 100      | μΑ    |
| or G             |   | or GND  | T <sub>A</sub> = -55°C to $+125$ °C           |          |      |       | 125      | μA    |

- Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except differential voltages V<sub>OD1</sub>, V<sub>OD2</sub>, V<sub>OD3</sub>.
  All typicals are given for V<sub>CC</sub> = +3.3V, T<sub>A</sub> = +25°C.
  This page efficiency limit is for compiler or the context (typicals are pixely to be stated at a time. The output (typicals are pixely to be stated at a time. The output (typicals are pixely typicals).

- Only one output shorted at a time. The output (true or complement) is configured High.
- This parameter does not meet the TIA/EIA-422-B specification.

# Switching Characteristics - Industrial (1) (2)

Over supply voltage and -40°C to +85°C operating temperature range, unless otherwise specified

|                   | Parameter   | Test Conditions  | Min | Тур  | Max | Units |
|-------------------|---|--|-----|------|-----|-------|
| t <sub>PHLD</sub> | Differential Propagation Delay High to Low                              | $R_L = 100\Omega$ , $C_L = 50 pF$<br>(Figure 3 and Figure 4) | 6   | 10.5 | 16  | ns    |
| t <sub>PLHD</sub> | Differential Propagation Delay Low to High                              |  | 6   | 11   | 16  | ns    |
| t <sub>SKD</sub>  | Differential Skew (same channel)  t <sub>PHLD</sub> - t <sub>PLHD</sub> |  |     | 0.5  | 2.0 | ns    |
| t <sub>SK1</sub>  | Skew, Pin to Pin (same device)  |  |     | 1.0  | 2.0 | ns    |
| t <sub>SK2</sub>  | Skew, Part to Part (3)  |  |     | 3.0  | 5.0 | ns    |
| t <sub>TLH</sub>  | Differential Transition Time<br>Low to High (20% to 80%)                |  |     | 4.2  | 10  | ns    |
| t <sub>THL</sub>  | Differential Transition Time<br>High to Low (80% to 20%)                |  |     | 4.7  | 10  | ns    |
| t <sub>PHZ</sub>  | Disable Time High to Z  | (Figure 5 Figure 6)  |     | 12   | 20  | ns    |
| t <sub>PLZ</sub>  | Disable Time Low to Z   |  |     | 9    | 20  | ns    |

- (1) f = 1 MHz,  $t_r$  and  $t_f \le 6 \text{ ns}$ , 10% to 90%.
- See TIA/EIA-422-B specifications for exact test conditions.
- Devices are at the same V<sub>CC</sub> and within 5°C within the operating temperature range

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# Switching Characteristics - Industrial (1) (2) (continued)

Over supply voltage and -40°C to +85°C operating temperature range, unless otherwise specified

|                  | Parameter                                  | Test Conditions | Min | Тур | Max | Units |
|------------------|--|-----------------|-----|-----|-----|-------|
| t <sub>PZH</sub> | Enable Time Z to High                      |                 |     | 22  | 32  | ns    |
| t <sub>PZL</sub> | Enable Time Z to Low                       |                 |     | 22  | 32  | ns    |
| f <sub>max</sub> | Maximum Operating Frequency <sup>(4)</sup> |                 | 32  |     |     | MHz   |

<sup>(4)</sup> All channels switching, output duty cycle criteria is 40%/60% measured at 50%. This parameter is guaranteed by design and

# Switching Characteristics - Military (1) (2)

Over supply voltage and -55°C to +125°C operating temperature range, unless otherwise specified

|                   | Parameter   | Test Conditions  | Min | Max | Units |
|-------------------|---|--|-----|-----|-------|
| t <sub>PHLD</sub> | Differential Propagation Delay High to Low                              | $R_L = 100\Omega$ , $C_L = 50 \text{ pF}$<br>(Figure 3 Figure 4) | 5   | 25  | ns    |
| t <sub>PLHD</sub> | Differential Propagation Delay Low to High                              |  | 5   | 25  | ns    |
| t <sub>SKD</sub>  | Differential Skew (same channel)  t <sub>PHLD</sub> - t <sub>PLHD</sub> |  |     | 5.0 | ns    |
| t <sub>SK1</sub>  | Skew, Pin to Pin (same device)  |  |     | 5.0 | ns    |
| t <sub>PHZ</sub>  | Disable Time High to Z  | (Figure 5 Figure 6)  |     | 35  | ns    |
| t <sub>PLZ</sub>  | Disable Time Low to Z   |  |     | 35  | ns    |
| t <sub>PZH</sub>  | Enable Time Z to High   |  |     | 40  | ns    |
| t <sub>PZL</sub>  | Enable Time Z to Low  |  |     | 40  | ns    |

 $<sup>\</sup>begin{array}{ll} \mbox{(1)} & \mbox{f} = 1 \mbox{ MHz, } t_r \mbox{ and } t_f \leq 6 \mbox{ ns, } 10\% \mbox{ to } 90\%. \\ \mbox{(2)} & \mbox{See TIA/EIA-422-B specifications for exact test conditions.} \end{array}$ 



#### PARAMETER MEASUREMENT INFORMATION

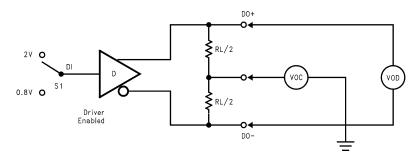


Figure 2. Differential Driver DC Test Circuit

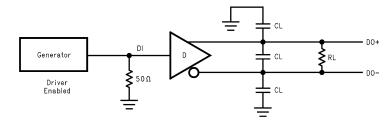
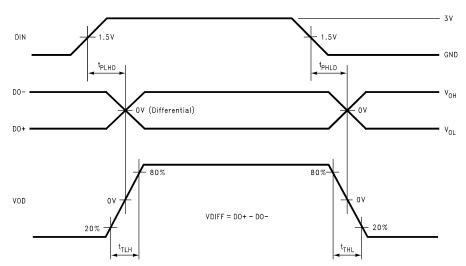


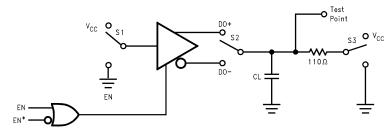
Figure 3. Differential Driver Propagation Delay and Transition Time Test Circuit



- A. Generator waveform for all tests unless otherwise specified: f = 1 MHz, Duty Cycle = 50%  $Z_0 = 50\Omega$ ,  $t_r \le 10$  ns,  $t_f \le 10$
- B. C<sub>L</sub> includes probe and fixture capacitance.

Figure 4. Differential Driver Propagation Delay and Transition Time Waveforms





If EN is the input, then  $EN^* = High$ If EN\* is the input, then EN = Low

Figure 5. Driver Single-Ended TRI-STATE Test Circuit

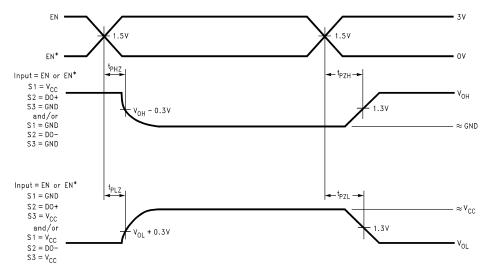


Figure 6. Driver Single-Ended TRI-STATE Waveforms



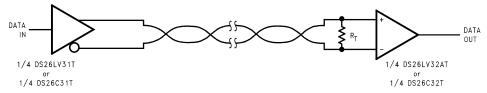
### **Typical Application Information**

General application guidelines and hints for differential drivers and receivers may be found in the following application notes:

- AN-214
- AN-457
- AN-805
- AN-847
- AN-903
- AN-912
- AN-916

#### Power Decoupling Recommendations:

Bypass caps must be used on power pins. High frequency ceramic (surface mount is recommended) 0.1 µF in parallel with 0.01 µF at the power supply pin. A 10 µF or greater solid tantalum or electrolytic should be connected at the power entry point on the printed circuit board.



R<sub>T</sub> is optional although highly recommended to reduce reflection.

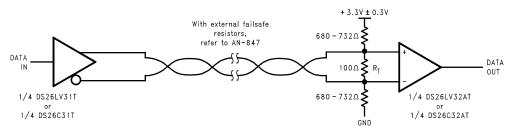


Figure 7. Typical Driver Connection

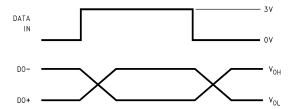


Figure 8. Typical Driver Output Waveforms

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## SNLS114C -MARCH 1999-REVISED FEBRUARY 2013



# **REVISION HISTORY**

| Cł | hanges from Revision B (February 2013) to Revision C | Pag | е |
|----|--|-----|---|
| •  | Changed layout of National Data Sheet to TI format   |     | 7 |



# PACKAGE OPTION ADDENDUM

24-Aug-2018

#### **PACKAGING INFORMATION**

| Orderable Device | Status | Package Type | _       | Pins | _    | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|----------------------------|------------------|--------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty  | (2)                        | (6)              | (3)                |              | (4/5)          |         |
| DS26LV31TM/NOPB  | ACTIVE | SOIC         | D       | 16   | 48   | Green (RoHS<br>& no Sb/Br) | CU SN            | Level-1-260C-UNLIM | -40 to 85    | DS26LV31<br>TM | Samples |
| DS26LV31TMX/NOPB | ACTIVE | SOIC         | D       | 16   | 2500 | Green (RoHS<br>& no Sb/Br) | CU SN            | Level-1-260C-UNLIM | -40 to 85    | DS26LV31<br>TM | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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24-Aug-2018

PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device           | Package<br>Type | Package<br>Drawing |    |      | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| DS26LV31TMX/NOPB | SOIC            | D                  | 16 | 2500 | 330.0                    | 16.4                     | 6.5        | 10.3       | 2.3        | 8.0        | 16.0      | Q1               |

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#### \*All dimensions are nominal

| ĺ | Device           | Package Type | Package Drawing Pins |    | SPQ  | Length (mm) | Width (mm) | Height (mm) |  |
|---|------------------|--------------|----------------------|----|------|-------------|------------|-------------|--|
| I | DS26LV31TMX/NOPB | SOIC         | D                    | 16 | 2500 | 367.0       | 367.0      | 35.0        |  |

# D (R-PDS0-G16)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.